

# UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.usplo.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
10/734,422	12/12/2003	Jeiwei Chang	HTIRC02-015	3911	
7590 05/15/2006		EXAMINER			
STEPHEN B. ACKERMAN 28 DAVIS AVENUE			CHACKO DAVIS, DABORAH		
	IE, NY 12603		ART UNIT	PAPER NUMBER	
	·		1756	- <del>-</del> -	
			DATE MAILED: 05/15/2006	5	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applic	ation No.	Applicant(s)				
Office Action Summary		10/734	1,422	CHANG ET AL.				
		Exami	ner	Art Unit				
		Dabora	ah Chacko-Davis	1756				
Period fe	The MAILING DATE of this community or Reply	nication appears on	the cover sheet wi	th the correspondence ac	idress			
WHI( - Exte after - If NC - Failt Any	ORTENED STATUTORY PERIOD FOR CHEVER IS LONGER, FROM THE MINISTRICT IN THE MINISTRICT IS LONGER, FROM THE MINISTRICT IS LONGER, FROM THE MINISTRICT IS LONGER IN THE MINISTRICT IS LONGER IN THE MINISTRICT IS LONGER IN THE MINISTRICT IN THE MINISTRICT IS LONGER IN THE MINISTRICT IN TH	MAILING DATE OF s of 37 CFR 1.136(a). In no munication. tatutory period will apply an y will, by statute, cause the	THIS COMMUNIC bevent, however, may a red d will expire SIX (6) MON application to become AB.	CATION.  Peply be timely filed  THS from the mailing date of this of the control				
Status								
1)[\]	Responsive to communication(s) fil	ed on 17 Anril 2006	3					
2a)□	, ,	2b)⊠ This action i	_					
3)	Since this application is in condition	•		ers incosecution as to the	e merits is			
-,_	closed in accordance with the pract		-	· •				
Disposit	ion of Claims	·		,				
	Claim(s) 1-38 is/are pending in the	annlication						
+/ك3	· · · · · · · · · · · · · · · · · · ·	* *	ronsideration					
5)□	4a) Of the above claim(s) <u>35-38</u> is/are withdrawn from consideration.  Claim(s) is/are allowed.							
′=	Claim(s) <u>1-34</u> is/are rejected.							
7)	Claim(s) is/are objected to.				•			
8)□	Claim(s) are subject to restri	ction and/or election	n requirement.					
,,	ion Papers							
_	•	- <b>-</b>						
	The specification is objected to by the		h)		•			
ا ال	The drawing(s) filed on is/are	•	•					
•	Applicant may not request that any objection				ED 4 4047 IV			
11)	Replacement drawing sheet(s) including The oath or declaration is objected t		· ·					
÷		o by the Examiner.	Note the attached	Office Action of form P				
Priority (	ınder 35 U.S.C. § 119							
	Acknowledgment is made of a claim ☐ All b)☐ Some * c)☐ None of:	for foreign priority	under 35 U.S.C. §	119(a)-(d) or (f).				
,	1. Certified copies of the priority	documents have b	een received.					
	2. Certified copies of the priority			oplication No				
	3. Copies of the certified copies				Stage			
	application from the Internation		•		· ·			
* 5	See the attached detailed Office action	on for a list of the ce	ertified copies not a	eceived.	-			
				·	-			
Attachmen	t(s)							
_	e of References Cited (PTO-892)		4) Interview S	ummary (PTO-413)				
2) 🔲 Notic	e of Draftsperson's Patent Drawing Review (F		Paper No(s)	/Mail Date				
	mation Disclosure Statement(s) (PTO-1449 or r No(s) <u>/</u> Mail Date <u>03/04</u> .	PTO/SB/08)	5) Notice of In	formal Patent Application (PT0 	<b>)-152)</b>			

Application/Control Number: 10/734,422

Art Unit: 1756

### .

Page 2

## DETAILED ACTION

## Election/Restrictions

1. Applicant's election with traverse of Group I, claims 1-34, in the reply filed on 04/17, 2006 is acknowledged. The traversal is on the ground(s) "that it is necessary to obtain claims in both the process and product claim language, and that the process claims necessarily use the product and viceversa. This is not found persuasive because the process can be used to make a materially different product such as VLSI circuits. Applicant's argument that the Examiner's suggestion is speculative has not been substantiated. Claims 35-38, are withdrawn from further consideration pursuant to 37 CFR 1.142(b), as being drawn to a nonelected invention, there being no allowable generic or linking claim.

The requirement is still deemed proper and is therefore made FINAL.

## Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1-34, are rejected under 35 U.S.C. 102(e) as being anticipated by U. S. Patent No. 6,643,107 (Hasegawa et al., hereinafter referred to as Hasegawa).

Art Unit: 1756

Hasegawa, in col 5, lines 55-67, in col 6, lines 1-24, and lines 33-55, in col 7, lines 1-67, in col 28, lines 6-12, in col 29, lines 48-67, in col 30, lines 6-12, in col 41, lines 40-67, discloses a method of forming a magnetic head comprising a spin valve that includes laminating a substrate, an anitferromagnetic layer, a seed layer (first pinned layer), a second pinned layer, a nonmagnetic conductive layer (spacer layer), a free magnetic layer (free layer), a protective layer (capping layer, Ta), an upper core layer (lead layer), and an insulating layer of alumina formed on the lead layer (upper core layer), forming a resist mask on the spin valve (GMR stack, a sheet of material of first thickness), wherein the width of the photoresist mask determines the width of the first pedestal (width R1), directing an ion beam at an angle relative to an axis perpendicular to the mask surface on the spin valve, wherein the substrate can be rotated or moved obliquely, the ion beam removing material in a region closest to the surface of the mask (undercut see figure 5), and removing material from a surface in the region extending outwards from a line (T10, shadowing effect of the mask) parallel of the side of the mask (forming a slope that extends outwards in the second pedestal region, see figure 3) at a distance from the mask as claimed (the distance determined by the height or thickness of the photoresist mask, causing the resist mask shadowing), and obliquely bombarding the stack with the ion beam as recited in the claims (the oblique angle of incidence of the beam at both sides being equal, symmetrical pedestal formation, see figures 8, and 12), thereby determining the width of the second pedestal, wherein the substrate can be obliquely moved or rotated with respect of the axis perpendicular to the surface of the substrate (claims 1, 9, 18, 25, 26-27). Hasegawa, in

Art Unit: 1756

col 29, lines 49-54, and in col 30, lines 7-10, the ion beam source can be stationary or obliquely moved, and that the substrate can be rotated or moved or kept stationary with respect to the axis perpendicular to the substrate surface (claims 2-4, 10-12).

Hasegawa, in col 28, lines 49-55, and in figures 2-3, and 5, discloses that the first angle and the second angle (angle A and angle B) are in the claimed ranges (shadowing effect angled ion beam impingement, and oblique incidence of the ion beam) (claims 5-6, 13-14, 21-22, 29, and 30). Hasegawa, in col 20, lines 5-57, in figures 5, and 12, discloses that the bottom pedestal is at least twice the width of the first pedestal (top pedestal) width with the claimed thickness, and the top pedestal possesses a steeper sidewall (undercut) than the bottom pedestal, and has the claimed aspect ratio, and thickness(claims 7-8, 15-17, 20, 23, 24, and 31-34). Hasegawa, in col 23, lines 25-47, and in col 24, lines 15-28, discloses that the magnetic head (spin valve magnetic material) has a GMR ratio of at least 1%, and less series resistance (less than 50 ohms) (claims 19, and 28).

#### Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Daborah Chacko-Davis whose telephone number is (571) 272-1380. The examiner can normally be reached on M-F 9:30 - 6:00. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mark F Huff can be reached on (571) 272-1385. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

dcd

May 11, 2006.

JOHN A MCPHERSON PRIMARY EXAMINER